

N-Channel 20-V (D-S) MOSFET

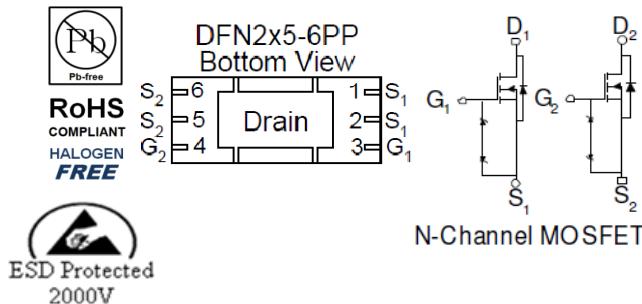
Key Features:

- Low $r_{DS(on)}$ trench technology
- Low thermal impedance
- Fast switching speed

PRODUCT SUMMARY		
V_{DS} (V)	$r_{DS(on)}$ (mΩ)	I_D (A)
20	22 @ $V_{GS} = 4.5V$	10.3
	28 @ $V_{GS} = 2.5V$	9.2

Typical Applications:

- White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ C$ UNLESS OTHERWISE NOTED)

Parameter	Symbol	Limit	Units
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	± 12	
Continuous Drain Current ^a	I_D	10.3	A
		7.4	
Pulsed Drain Current ^b	I_{DM}	40	
Continuous Source Current (Diode Conduction) ^a	I_S	2.3	A
Power Dissipation ^a	P_D	3.5	W
		1.8	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55 to 150	°C

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Maximum	Units
Maximum Junction-to-Ambient ^a	$R_{\theta JA}$	36	°C/W
		76	

Notes

- Surface Mounted on 1" x 1" FR4 Board.
- Pulse width limited by maximum junction temperature

Electrical Characteristics

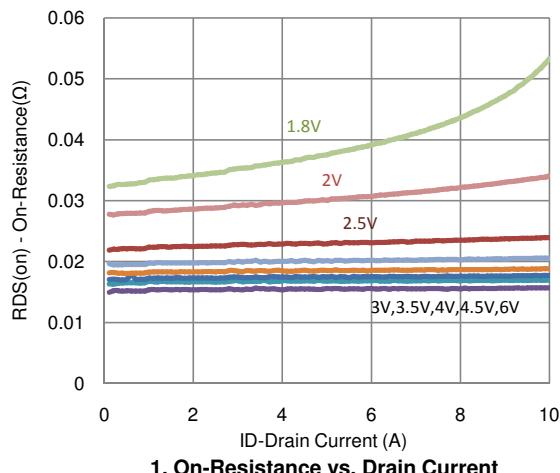
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static						
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	0.5			V
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 V$, $V_{GS} = \pm 12 V$			± 10	μA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 16 V$, $V_{GS} = 0 V$		1		μA
		$V_{DS} = 16 V$, $V_{GS} = 0 V$, $T_J = 55^\circ C$			25	
On-State Drain Current ^a	$I_{D(on)}$	$V_{DS} = 5 V$, $V_{GS} = 10 V$	20			A
Drain-Source On-Resistance ^a	$r_{DS(on)}$	$V_{GS} = 4.5 V$, $I_D = 8.8 A$		18	22	$m\Omega$
		$V_{GS} = 3.8 V$, $I_D = 8.2 A^b$		20	24	
		$V_{GS} = 3.1 V$, $I_D = 7.6 A^b$		21	26	
		$V_{GS} = 2.5 V$, $I_D = 7.1 A$		23	28	
Forward Transconductance ^a	g_{fs}	$V_{DS} = 15 V$, $I_D = 8.8 A$		20		S
Diode Forward Voltage ^a	V_{SD}	$I_S = 1.2 A$, $V_{GS} = 0 V$		0.7		V
Dynamic ^b						
Total Gate Charge	Q_g	$V_{DS} = 10 V$, $V_{GS} = 4.5 V$, $I_D = 8.8 A$		15		nC
Gate-Source Charge	Q_{gs}			4.1		
Gate-Drain Charge	Q_{gd}			4.7		
Turn-On Delay Time	$t_{d(on)}$	$V_{DS} = 10 V$, $R_L = 1.2 \Omega$, $I_D = 8.8 A$, $V_{GEN} = 4.5 V$, $R_{GEN} = 6 \Omega$		390		ns
Rise Time	t_r			970		
Turn-Off Delay Time	$t_{d(off)}$			4350		
Fall Time	t_f			3200		
Input Capacitance	C_{iss}	$V_{DS} = 15 V$, $V_{GS} = 0 V$, $f = 1 MHz$		630		pF
Output Capacitance	C_{oss}			105		
Reverse Transfer Capacitance	C_{rss}			100		

Notes

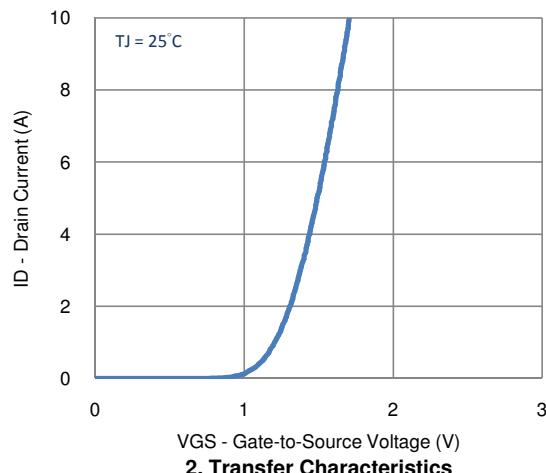
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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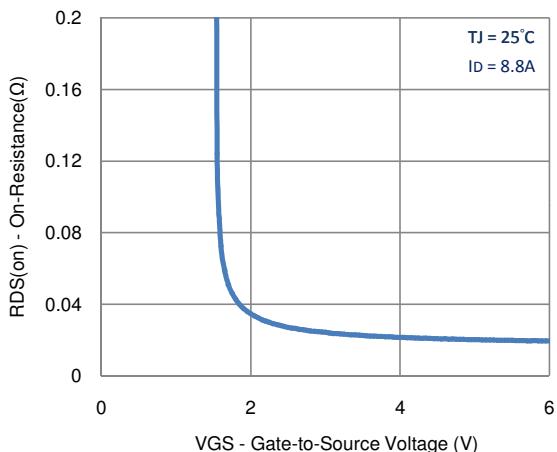
Typical Electrical Characteristics



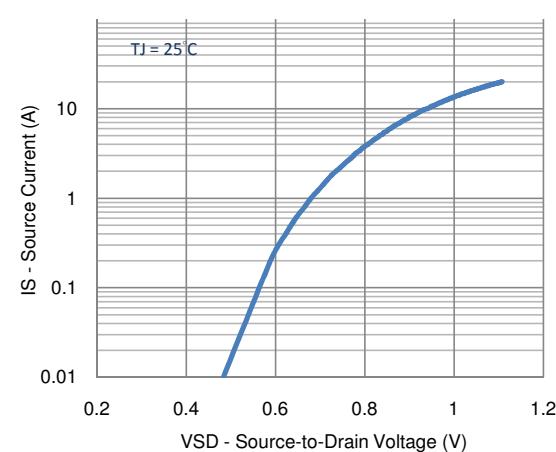
1. On-Resistance vs. Drain Current



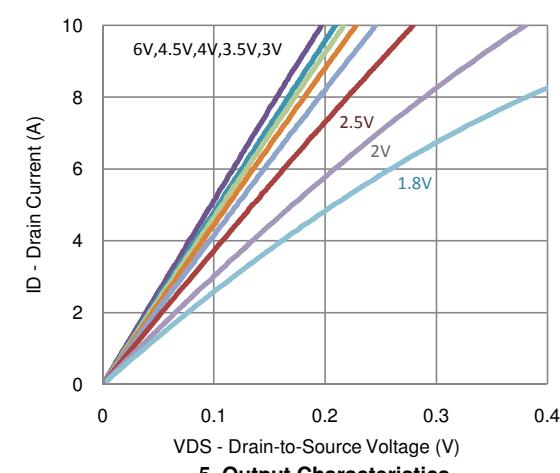
2. Transfer Characteristics



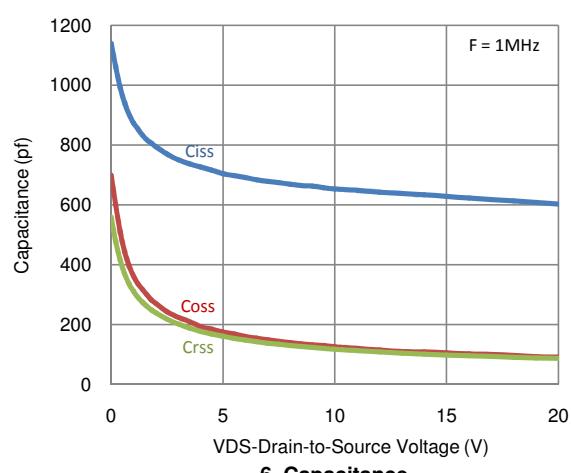
3. On-Resistance vs. Gate-to-Source Voltage



4. Drain-to-Source Forward Voltage

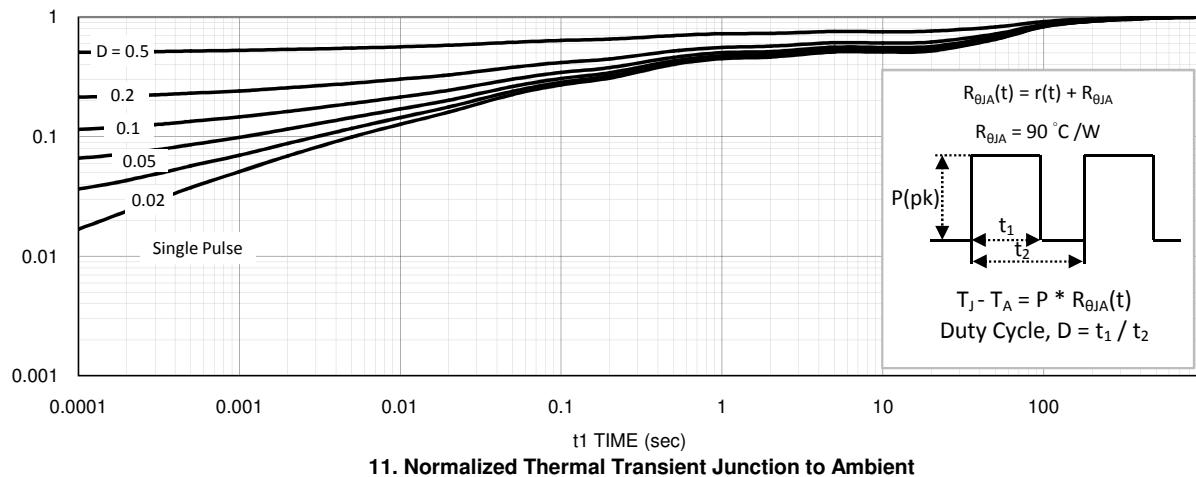
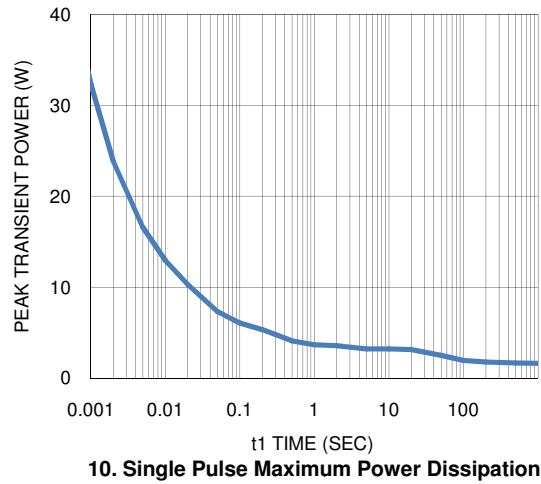
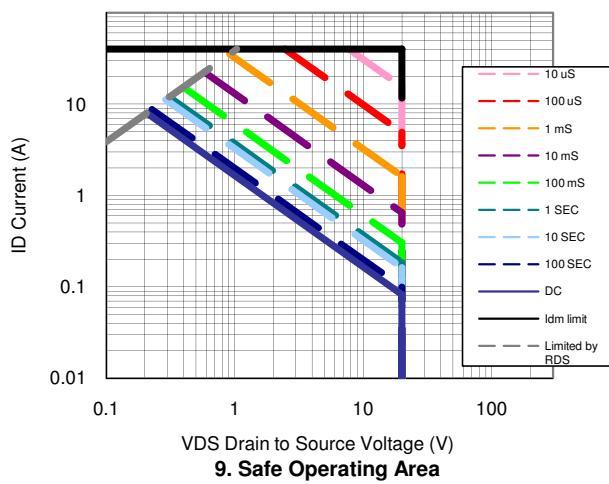
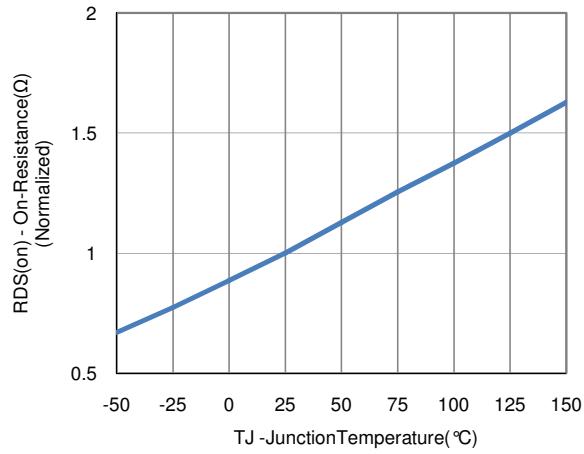
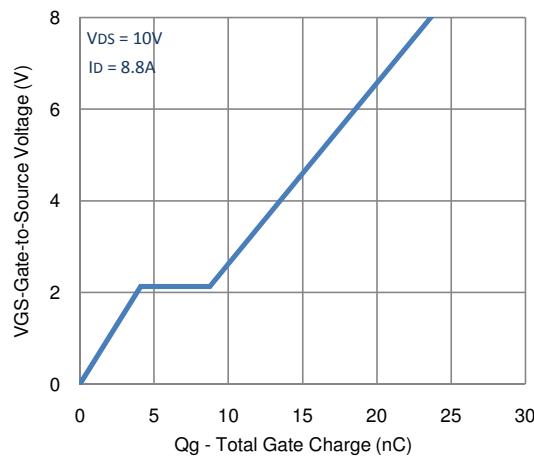


5. Output Characteristics

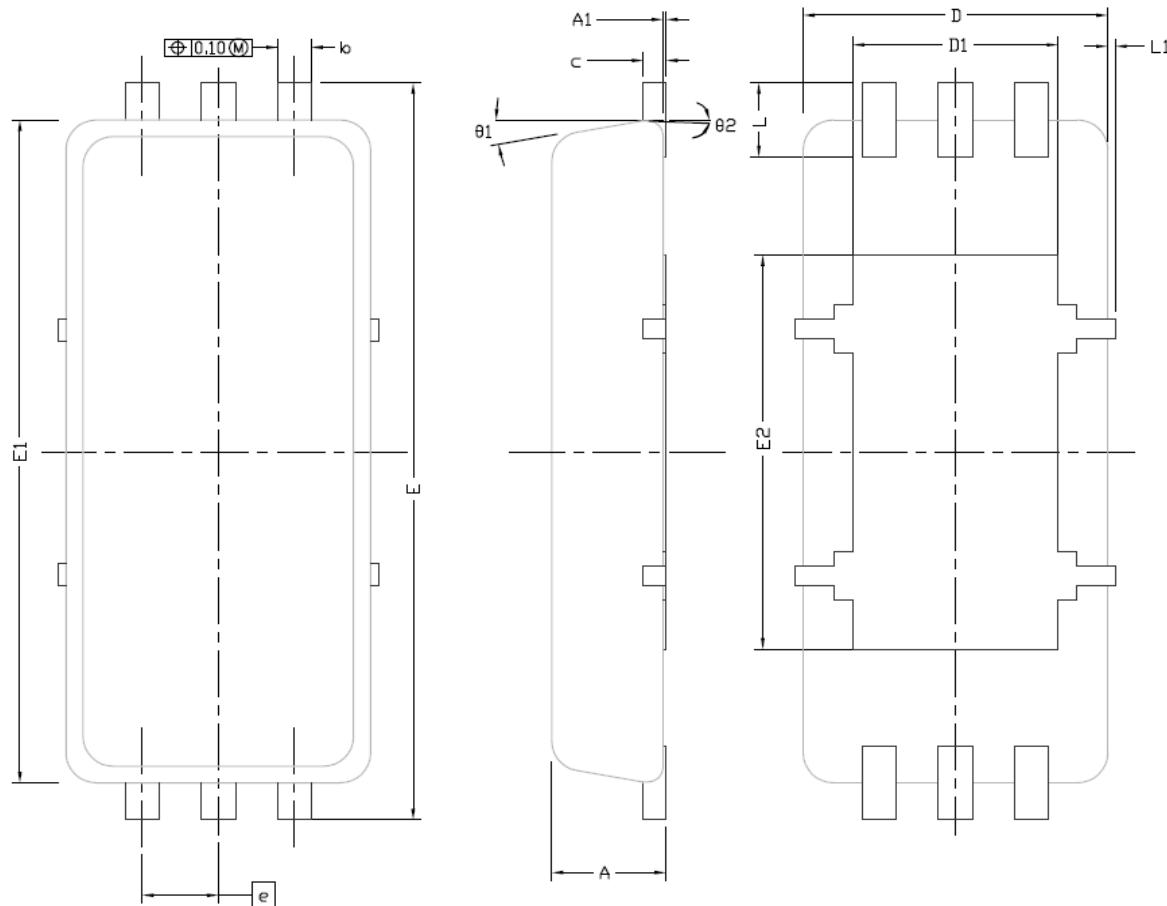


6. Capacitance

Typical Electrical Characteristics



Package Information



DIM.	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.70	0.75	0.80	0.028	0.030	0.0315
A1	0.00	---	0.05	0.000	---	0.002
b	0.20	0.225	0.30	0.008	0.009	0.012
c	0.10	0.152	0.20	0.004	0.006	0.008
D	2.00 BSC			0.079 BSC		
D1	1.30	1.35	1.55	0.051	0.053	0.061
E	5.00 BSC			0.197 BSC		
E1	4.50 BSC			0.177 BSC		
E2	2.60	2.67	2.95	0.102	0.105	0.116
e	0.50 BSC			0.020 BSC		
L	0.40	0.50	0.500	0.016	0.0197	0.0236
L1	0	---	0.100	0	---	0.004
theta1	0°	10°	12°	0°	10°	12°
theta2	3° BSC			3° BSC		